SLOS096 - D942, FEBRUARY 1971 - REVISED MAY 1988

- Common-Mode Input Range . . . ±10 V Typical
- Designed to Be Interchangeable With Fairchild μΑ709Α, μΑ709, and μΑ709C
- Maximum Peak-to-Peak Output Voltage Swing . . . 28-V Typical With 15-V Supplies

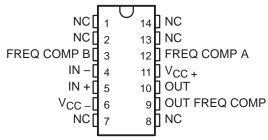
description

These circuits are general-purpose operational amplifiers. each having high-impedance differential inputs and a low-impedance output. Component matching, inherent with silicon monolithic circuit-fabrication techniques. produces an amplifier with low-drift and low-offset characteristics. Provisions are incorporated within the circuit whereby external components may be used to compensate the amplifier for stable operation under various feedback or load conditions. These amplifiers are particularly useful for applications requiring transfer or generation of linear or nonlinear functions.

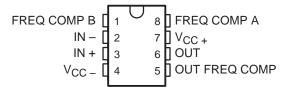
The uA709A circuit features improved offset characteristics, reduced input-current requirements, and lower power dissipation when compared to the uA709 circuit. In addition, maximum values of the average temperature coefficients of offset voltage and current are specified for the uA709A.

The uA709C is characterized for operation from 0°C to 70°C. The uA709AM and uA709M are characterized for operation over the full military temperature range of -55°C to 125°C.

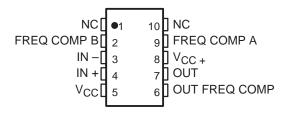
uA709AM, uA709M . . . J OR W PACKAGE (TOP VIEW)



uA709AM, uA709M... JG PACKAGE uA709C...D, JG, OR P PACKAGE (TOP VIEW)

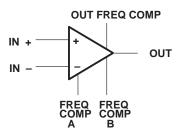


uA709AM, uA709M . . . U FLAT PACKAGE
(TOP VIEW)



NC - No internal connection

symbol



AVAILABLE OPTIONS

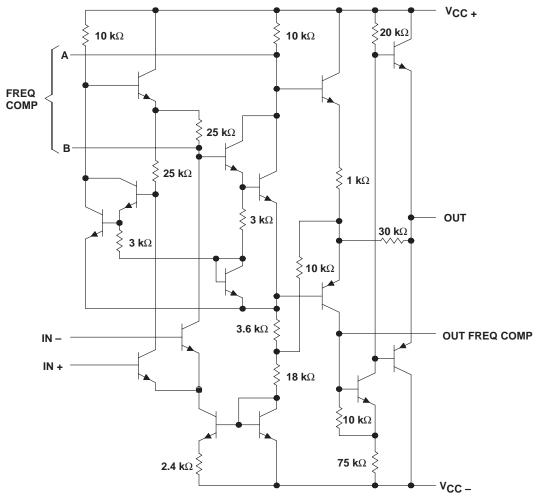
	V. a may	PACKAGE								
TA	V _{IO} max AT 25°C	SMALL OUTLINE (D)	CERAMIC (J)	CERAMIC DIP (JG)	PLASTIC DIP (P)	FLAT PACK (U)	FLAT PACK (W)			
0°C to 70°C	7.5 mV	uA709CD	_	uA709CJG	uA709CP	_	_			
−55°C	5 mV		uA709MJ	uA709MJG		uA709MU	uA709MW			
to 125°C	2 mV	_	uA709AMJ	uA709AMJG	_	uA709AMU	uA709AMW			

The D package is available taped and reeled. Add the suffix R to the device type when ordering, (e.g., uA709CDR).



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schematic



Component values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		uA709C	uA709M uA709AM	UNIT
Supply voltage, V _{CC+} (see Note 1)		18	18	V
Supply voltage, V _{CC} (see Note 1)	-18	-18	V	
Differential input voltage (see Note 2)	±5	±5	V	
Input voltage (either input, see Notes 1 and 3)	±10	±10	V	
Duration of output short circuit (see Note 4)	5	5	S	
Continuous total power dissipation		See Dissipation Rating Table		
Operating free-air temperature range		0 to 70	-55 to 125	°C
Storage temperature range	-65 to 150	-65 to 150	°C	
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	J, JG, U, or W package	300	300	°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D or P package	260		°C

- NOTES: 1. All voltage values, unless otherwise noted, are with respect to the midpoint between V_{CC+} and V_{CC-} .
 - 2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.
 - 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 10 V, whichever is less.
 - 4. The output may be shorted to ground or either power supply.



uA709C, uA709M, uA709AM GENERAL-PURPOSE OPERATIONAL AMPLIFIERS

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DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{\scriptsize A}} \le 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	DERATING FACTOR	DERATE ABOVE T _A	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING
D	300 mW	N/A	N/A	300 mW	N/A
J (uA709_M)	300 mW	11.0 mW/°C	123°C	300 mW	275 mW
JG (uA709_M)	300 mW	8.4 mW/°C	114°C	300 mW	210 mW
JG (uA709C)	300 mW	N/A	N/A	300 mW	N/A
Р	300 mW	N/A	N/A	300 mW	N/A
U	300 mW	5.4 mW/°C	94°C	300 mW	135 mW
W	300 mW	8.0 mW/°C	113°C	300 mW	200 mW

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electrical characteristics at specified free-air temperature, V_{CC \pm} = \pm 9 V to \pm 15 V (unless otherwise noted)

	DADAMETED	+		T _A ‡	u/	4709AM	С		uA709M			
	PARAMETER	TEST CON	TEST CONDITIONS†		MIN	TYP§	MAX	MIN	TYP§	MAX	UNIT	
\/\c	Input offeet voltege	Vo = 0	D- <40 l-0	25°C		0.6	2		1	5	mV	
VIO	Input offset voltage	$V_O = 0$,	R _S ≤ 10 kΩ	Full range			3			6		
αΛΙΟ	Average temperature coefficient of input	V _O = 0,	$R_S = 50 \Omega$	Full range		1.8	10		3		μV/°C	
	offset voltage	V _O = 0,	$R_S = 10 \text{ k}\Omega$	Full range		4.8	25		6		μν/ Ο	
				25°C		10	50		50	200		
lιΟ	Input offset current	VO = 0		−55°C		40	250		100	500	nA	
				125°C		3.5	50		20	200		
	Average temperature	\\\\ \(\) = 0		−55°C to 25°C		0.45	2.8				2V/0C	
αVIO	coefficient of input offset voltage	V _O = 0		25°C to 125°C		0.08	0.5				nA/°C	
1	lament bina animant	V= 0		25°C		0.1	0.2		0.2	0.5	μА	
lΒ	Input bias current	ΛO = 0		−55°C		0.3	0.6		0.5	1.5		
V/10.5	Common-mode	Vaa. = ±15.V		25°C	±8	±10		±8	±10		V	
VICR	input voltage range	$V_{CC\pm} = \pm 15 \text{ V}$		Full range	±8			±8			v	
	Maximum peak-to-peak output voltage swing	V _{CC±} = ±15 V,	Pr > 10 kO	25°C	24	28		24	28		V	
\/o(pp)				Full range	24			24				
VO(PP)		$V_{CC\pm} = \pm 15 \text{ V},$		25°C	20	26		20	26] '	
		$V_{CC\pm} = \pm 15 \text{ V},$	$R_L \ge 2 k\Omega$	Full range	20			20				
AVD	Large-signal differential voltage amplification	$V_{CC\pm} = \pm 15 \text{ V},$	R _L ≥ 2 kΩ,	25°C		45			45		V/mV	
AVD		$V_0 = \pm 10 \text{ V}$		Full range	25		70	25		70		
rį	Input resistance			25°C	350	750		150	400		kΩ	
''	Input resistance			−55°C	85	185		40	100		1/42	
r _O	Output resistance	$V_{O} = 0,$	See Note 5	25°C		150			150		Ω	
CMRR	Common-mode	V _{IC} = V _{ICR} min		25°C	80	110		70	90		dB	
O.V.II C.	rejection ratio	VIC - VICKIIIII		Full range	80			70			<u> </u>	
kSVS	Power supply sensitivity	$V_{CC} = \pm 9 \text{ V to}$	± 15 V	25°C		40	100		25	150	μV/V	
-373	(ΔV _{IO} / ΔV _{CC})			Full range			100			150		
		$V_{CC\pm} = \pm 15 \text{ V},$	No load	25°C		2.5	3.6		2.6	5.5		
ICC	Supply current	$V_0 = 0$	i to ioau,	−55°C		2.7	4.5				mA	
		<u> </u>		125°C		2.1	3					
		$V_{CC\pm} = \pm 15 \text{ V},$	No load.	25°C		75	108		78	165		
P_{D}	Total power dissipation	$V_0 = 0$		−55°C		81	135		-		mW	
				125°C		63	90					

[†] All characteristics are specified under open-loop with zero common-mode input voltage unless otherwise specified.

NOTE 5: This typical value applies only at frequencies above a few hundred hertz because of the effects of drift and thermal feedback.



[‡] Full range for uA709C is 0°C to 70°C. Full range for uA709AM and uA709M is -55°C to 125°C.

[§] All typical values are at $V_{CC\pm} = \pm 15 \text{ V}$.

electrical characteristics at specified free-air temperature (unless otherwise noted V_{CC \pm} = \pm 15 V)

	PARAMETER		NOTIONST	TA∓	uA709C			UNIT
			TEST CONDITIONS†		MIN	TYP	MAX	UNII
V	land offertualte as	$V_{CC\pm} = \pm 9 \text{ V to } \pm 15 \text{ V, } V_{O} = 0$		25°C		2	7.5	mV
VIO	Input offset voltage			Full range			10	IIIV
li a	Input offset current	$V_{CC\pm} = \pm 9 \text{ V to } \pm 15 \text{ V, } V_O = 0$		25°C		100	500	nA
liO				Full range			750	
1	lanut higa gurrant	$V_{CC\pm} = \pm 9 \text{ V to } \pm 15 \text{ V, } V_{O} = 0$		25°C		0.3	1.5	μΑ
lВ	Input bias current			Full range			2	
VICR	Common-mode input voltage range			25°C	±8	±10		V
	Maximum peak-to-peak output voltage swing	R _L ≥ 10 kΩ		25°C	24	28		V
\/- (==)				Full range	24			
VO(PP)		$R_L = 2 k\Omega$		25°C	20	26		V
		$R_L \ge 2 k\Omega$		Full range	20			
AVD	Large-signal differential	D. < 2 kO	V _O = ± 10 V	25°C	15	45		\//m\/
	voltage amplification	$R_L \le 2 k\Omega$,		Full range	12			V/mV
	Input resistance			25°C	50	250		1.0
ri				Full range	35			kΩ
r _o	Output resistance	V _O = 0,	See Note 5	25°C		150		Ω
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICR} min		25°C	65	90		dB
ksvs	Supply voltage sensitivity	$V_{CC} = \pm 9 \text{ V to } \pm$:15 V	25°C		25	200	μV/V
PD	Total power dissipation	$V_0 = 0$,	No load	25°C		80	200	mW

[†] All characteristics are specified under open-loop operation with zero volts common-mode voltage unless otherwise specified.

NOTE 5: This typical value applies only at frequencies above a few hundred hertz because of the effects of drift and thermal feedback.

operating characteristics, V_{CC \pm} = \pm 9 V to \pm 15 V, T_A = 25°C

PARAMETER		TEST CONDITIONS†					uA709C uA709M uA709AM		
							TYP	MAX	1
t _r	Rise time	$V_1 = 20 \text{ mV},$	$R_1 = 2 k\Omega$	See Figure 1	C _L = 0		0.3	1	μs
	Overshoot factor	V ₁ = 20 IIIV,	TYL - 2 K32,		C _L = 100 pF		6%	30%	

PARAMETER MEASUREMENT INFORMATION

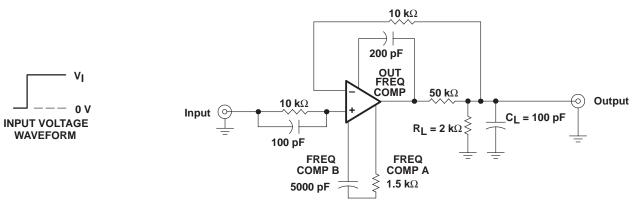


Figure 1. Rise Time and Slew Rate Test Circuit



[‡] Full range for uA709C is 0°C to 70°C. Full range for uA709AM and uA709M is -55°C to 125°C.

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